NSN 5961-00-068-5779

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View Online at https://aerobasegroup.com/nsn/5961-00-068-5779 **Inclosure Material:** Metal **Overall Length:** 0.344 inches **Overall Diameter:** 0.648 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.672 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 10.0 breakdown voltage, emitter-to-base, collector open and 60.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** Between 3.00 amperes source cutoff current and 7.50 amperes source cutoff current **Power Rating Per Characteristic:** 425.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

No